

Electronic Supplementary Information

Quinoxaline-based thermally activated delayed fluorescence emitters for highly efficient organic light emitting diode

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1. CV curves of Br-TTPZ and NMR Spectra

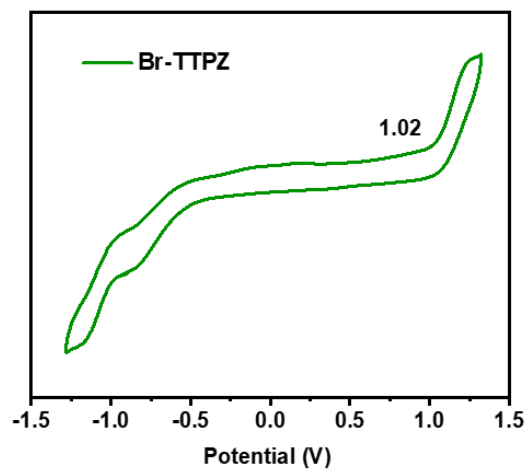


Figure S1. Cyclic voltammogram of Br-TTPZ.

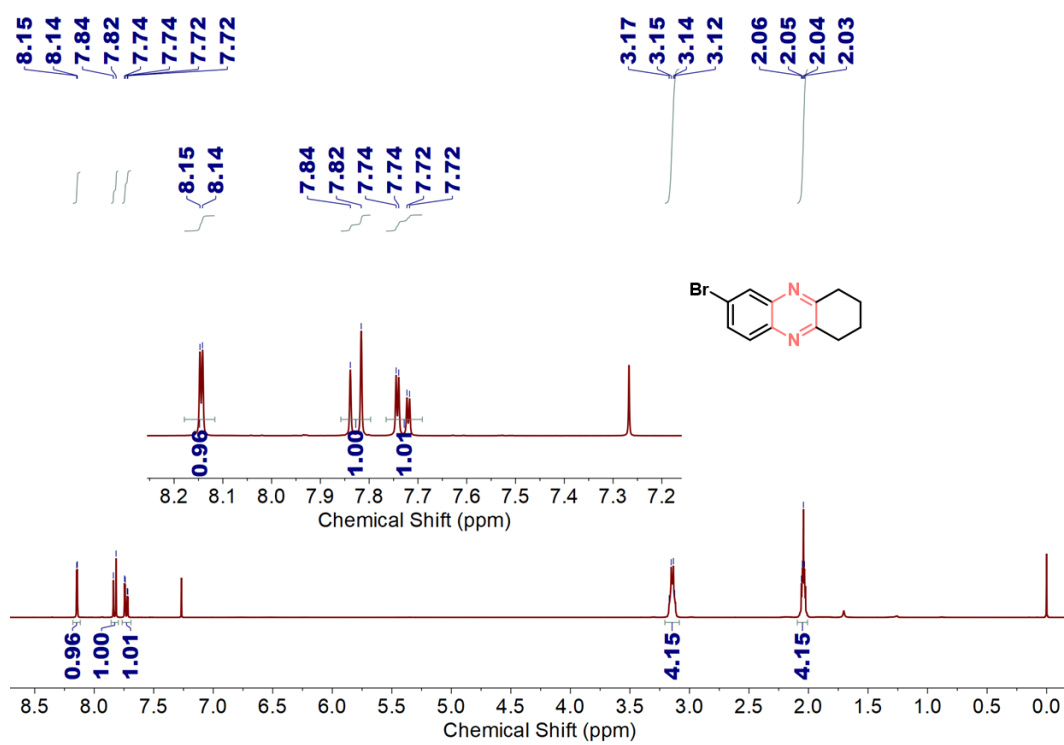


Figure S2. ¹H NMR spectrum of Br-TTPZ.

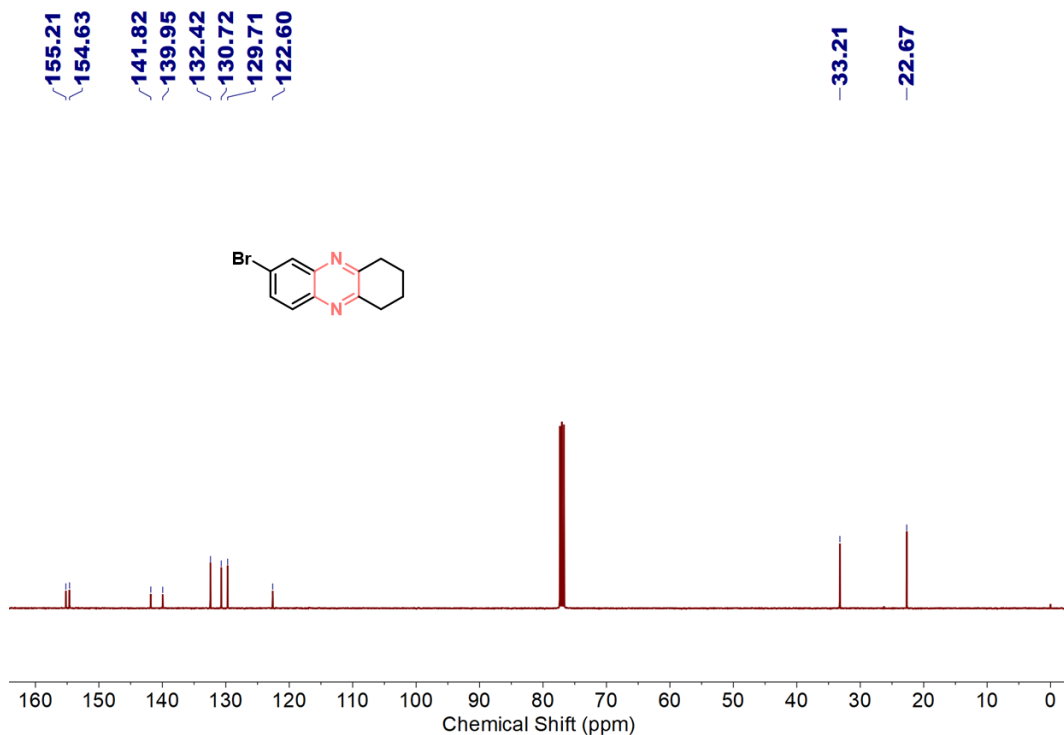


Figure S3. ^{13}C NMR spectrum of Br-TTPZ.

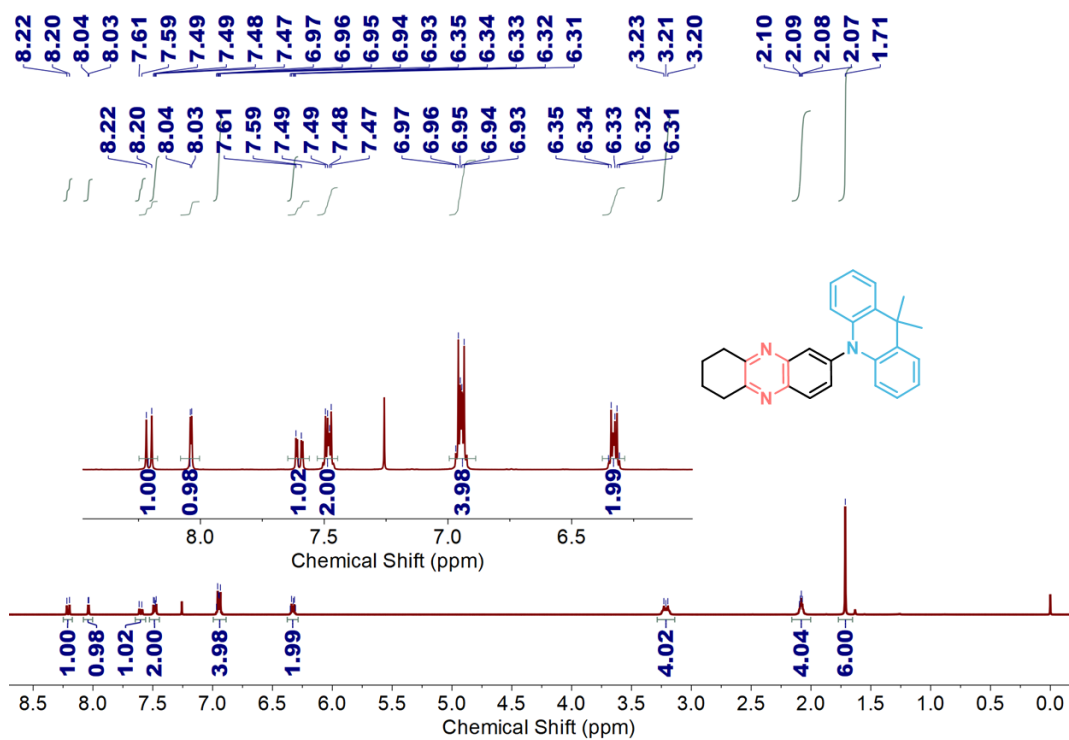


Figure S4. ^1H NMR spectrum of DMAC-TTPZ.

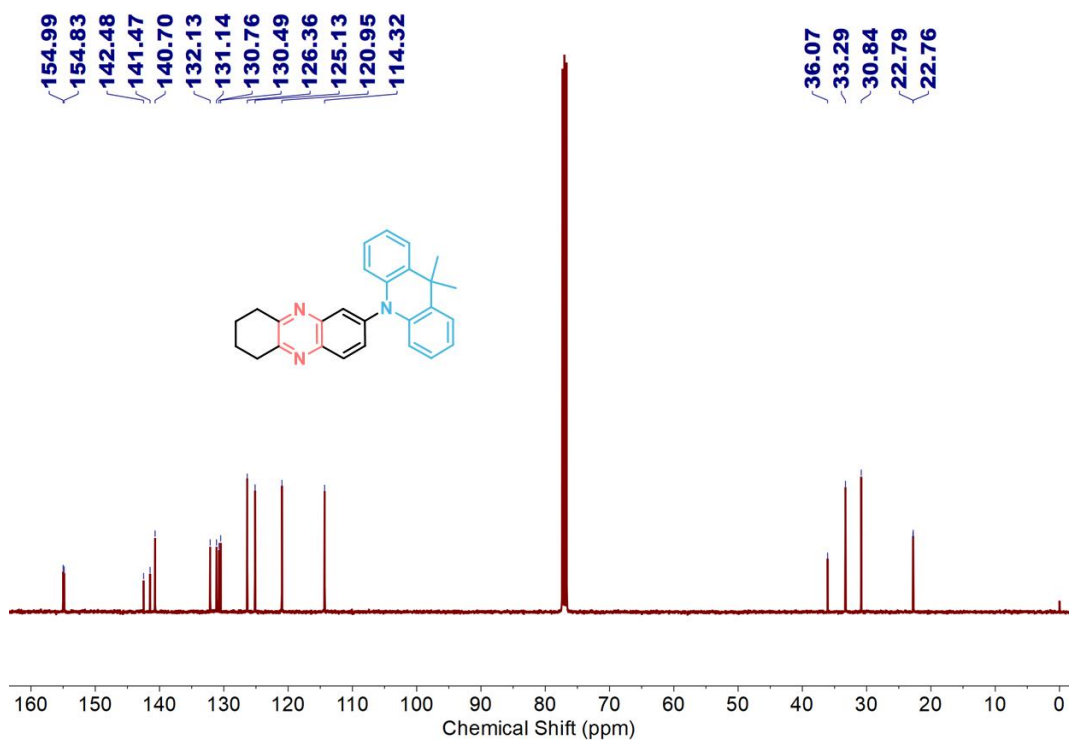


Figure S5. ¹³C NMR spectrum of DMAC-TTPZ.

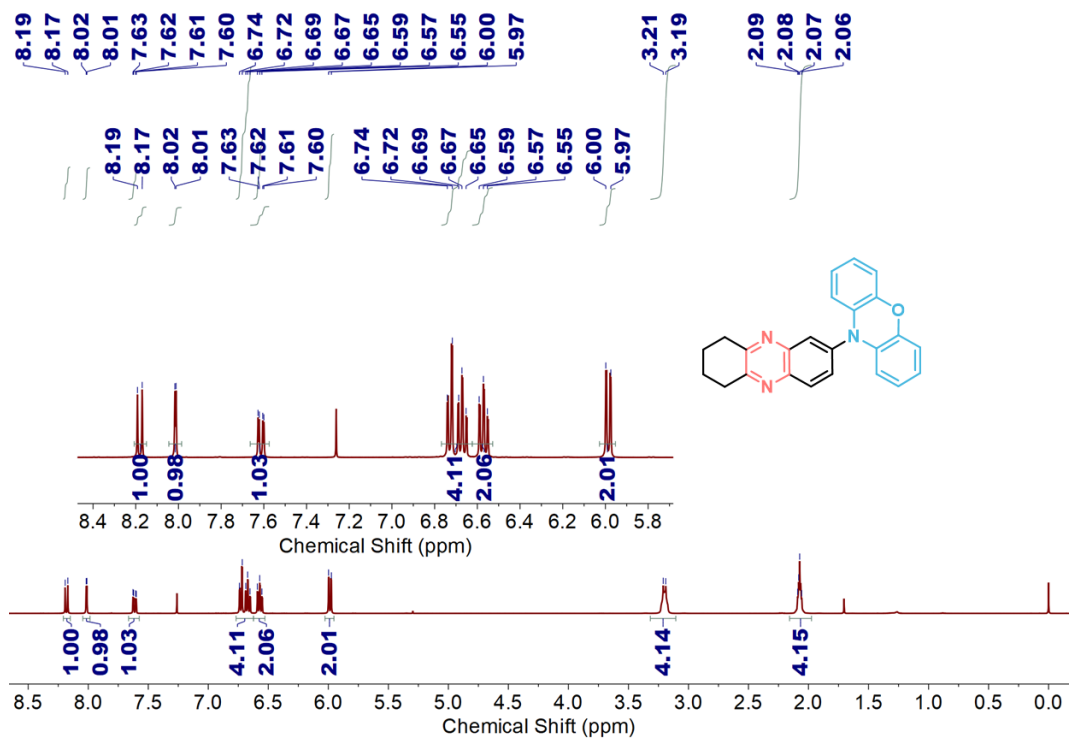


Figure S6. ¹H NMR spectrum of PXZ-TTPZ.

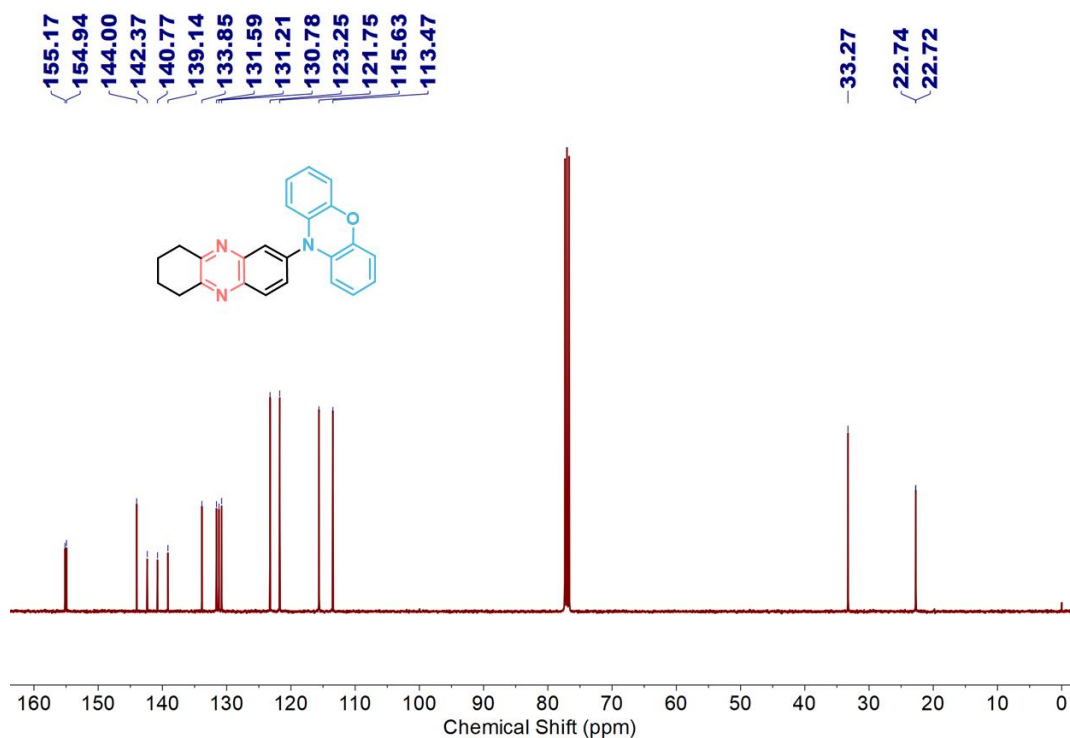


Figure S7. ¹³C NMR spectrum of PXZ-TTPZ.

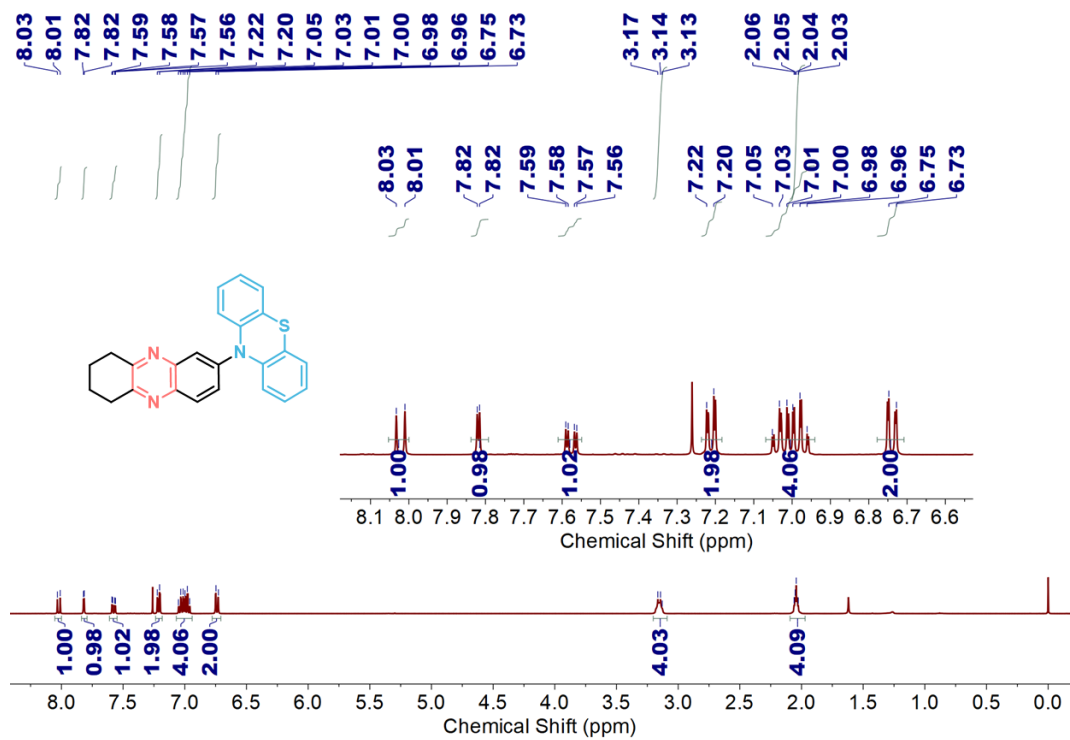


Figure S8. ¹H NMR spectrum of PTZ-TTPZ.

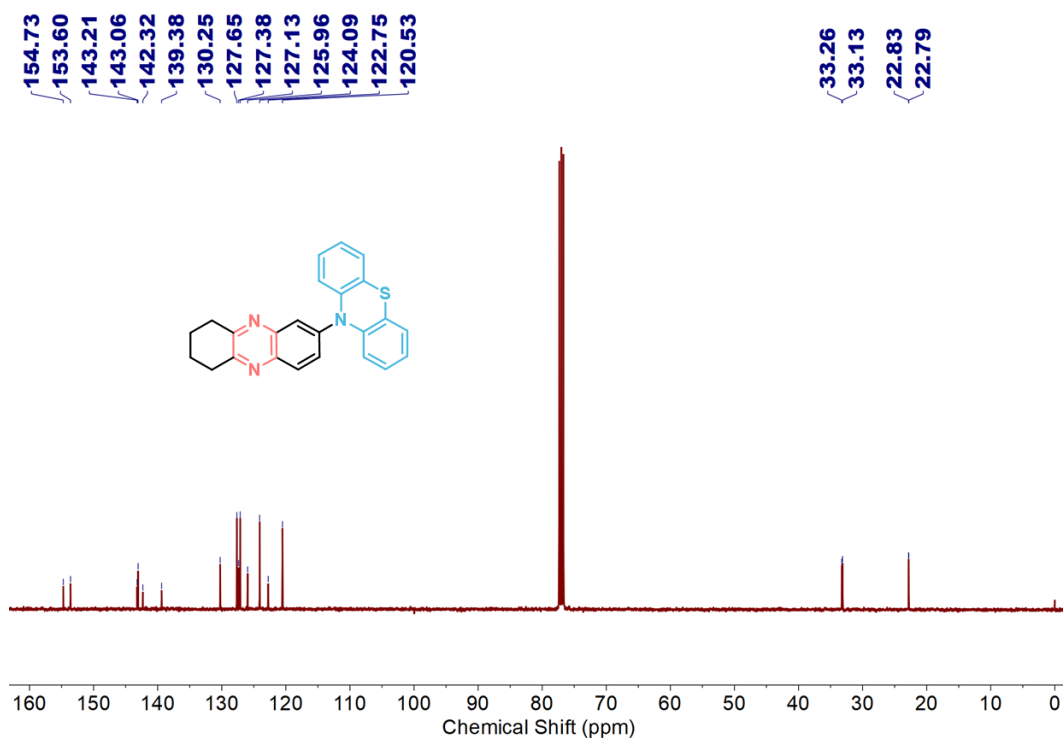


Figure S9. ^{13}C NMR spectrum of PTZ-TTPZ.

2. HRMS Spectra

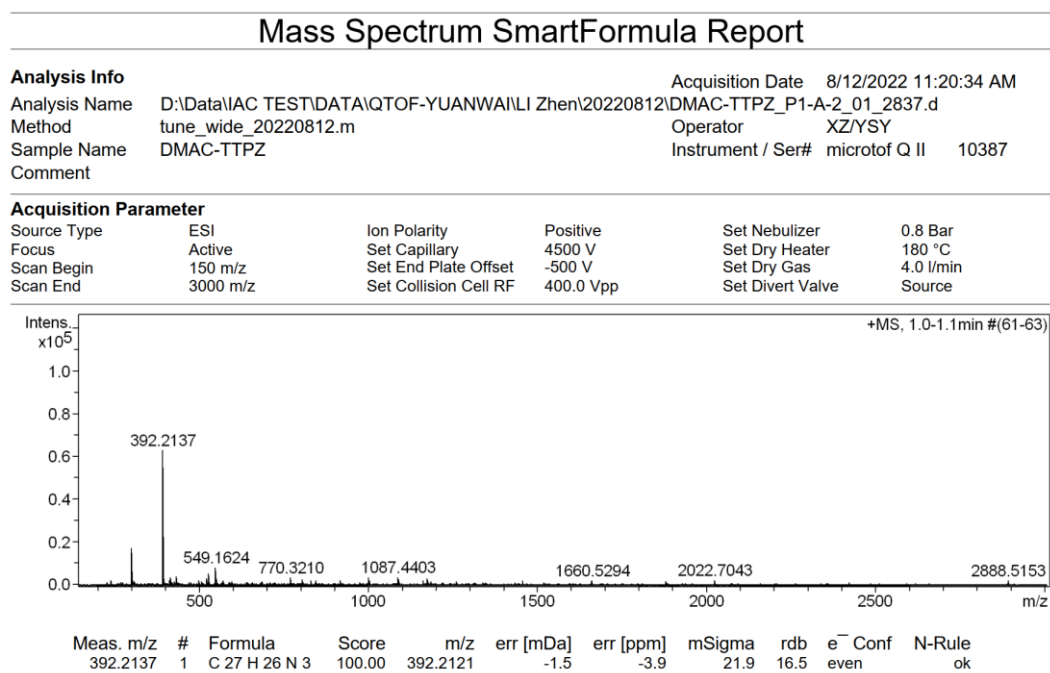


Figure S10. HRMS spectrum of DMAC-TTPZ.

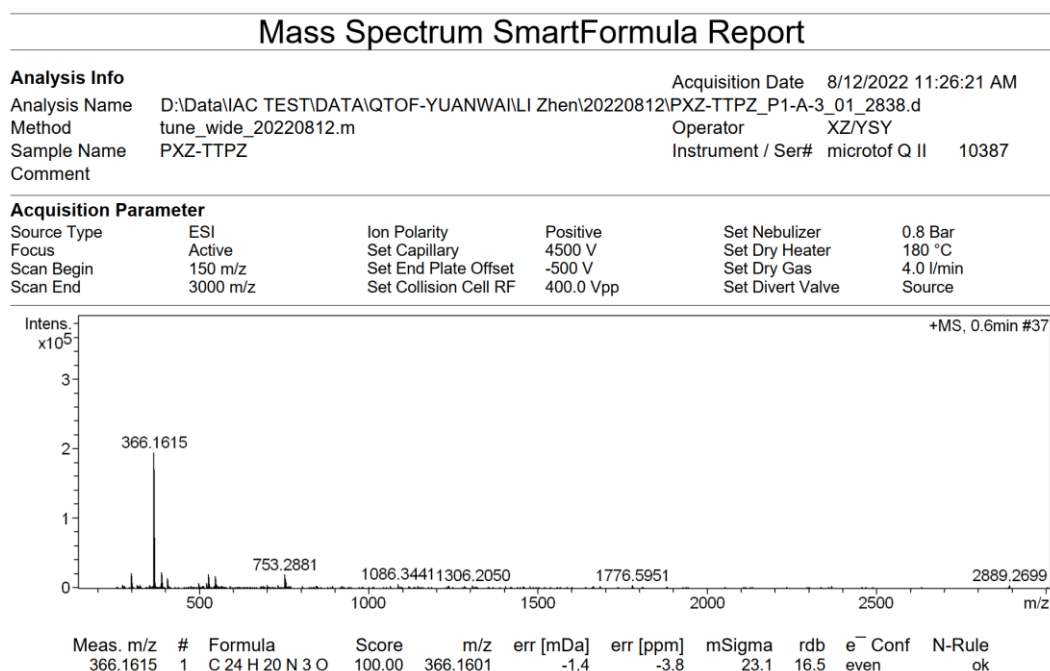


Figure S11. HRMS spectrum of PXZ-TTPZ.

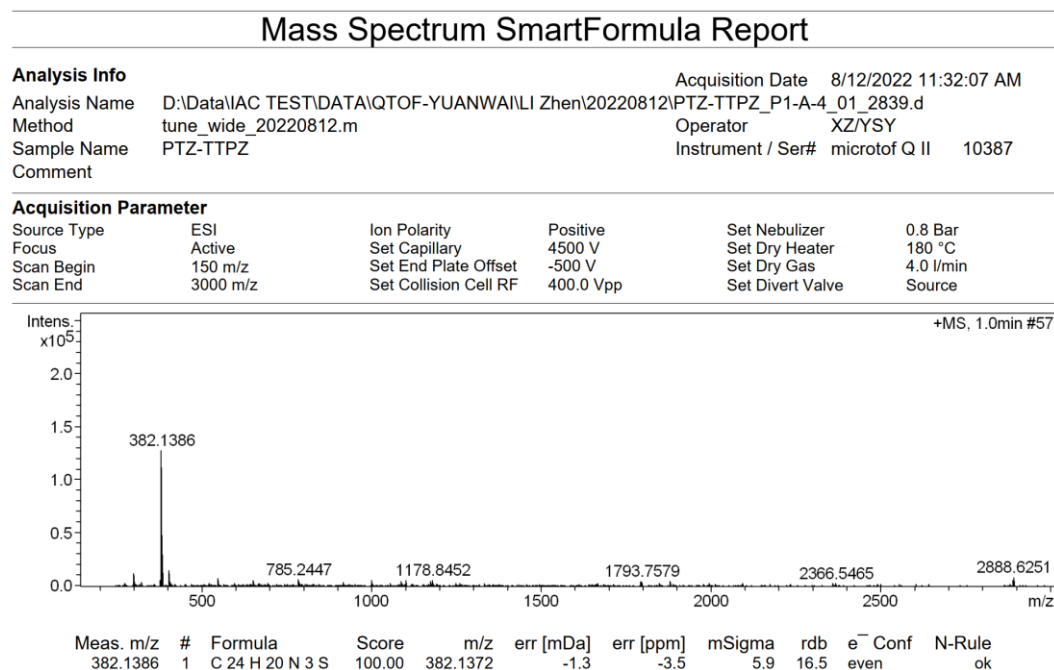


Figure S12. HRMS spectrum of PTZ-TTPZ.

3. DSC Voltammogram

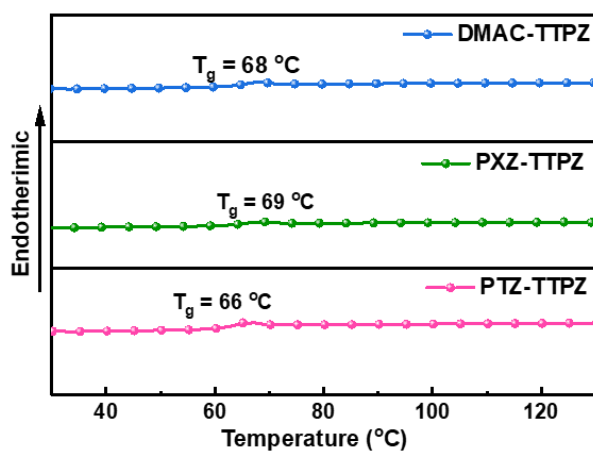


Figure S13. DSC voltammogram of DMAC-TTPZ, PXZ-TTPZ, and PTZ-TTPZ.

4. Photophysical Properties

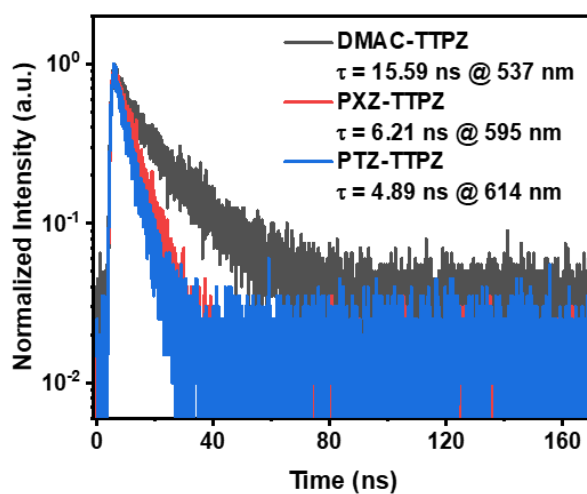


Figure S14. Time-resolved PL decay curves of DMAC-TTPZ, PXZ-TTPZ, and PTZ-TTPZ in toluene solution ($5 \times 10^{-5}\text{ mol L}^{-1}$) under N_2 atmosphere.

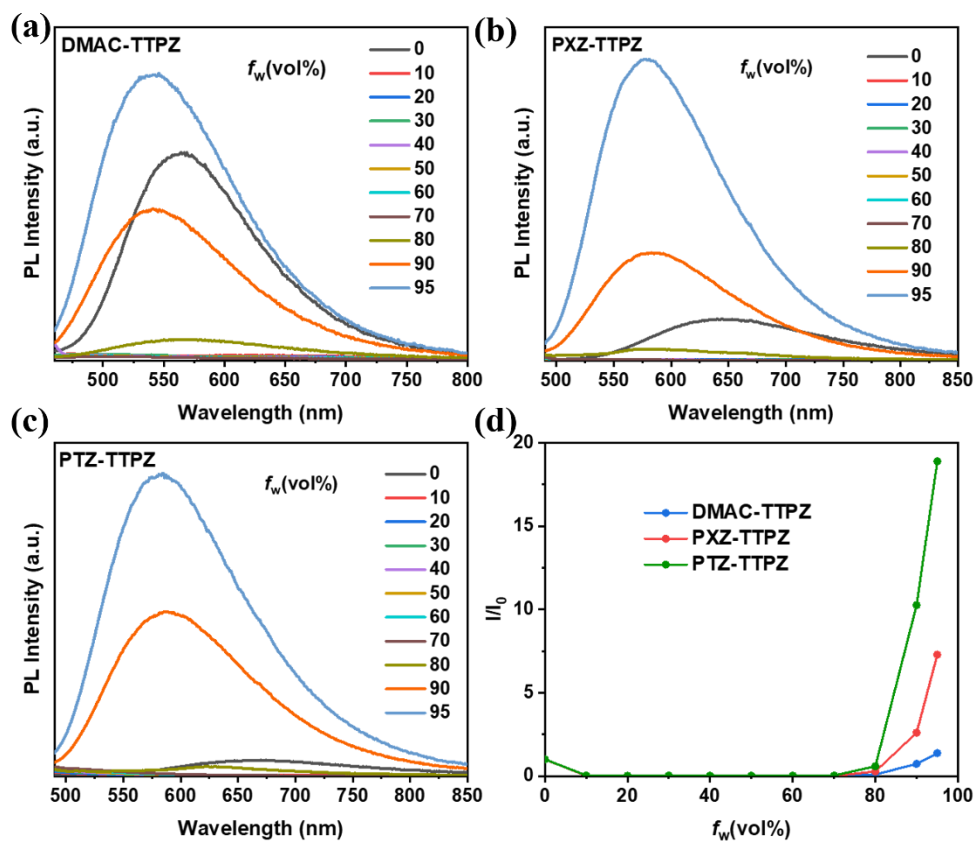


Figure S15. PL spectra of DMAC-TTPZ (a), PXZ-TTPZ (b), and PTZ-TTPZ (c) in THF-water mixtures with different water fractions (f_w). Concentration: 5×10^{-5} mol L⁻¹. (d) Plots of I/I_0 versus f_w for DMAC-TTPZ, PXZ-TTPZ, and PTZ-TTPZ. I_0 is the PL intensity in pure THF solution.

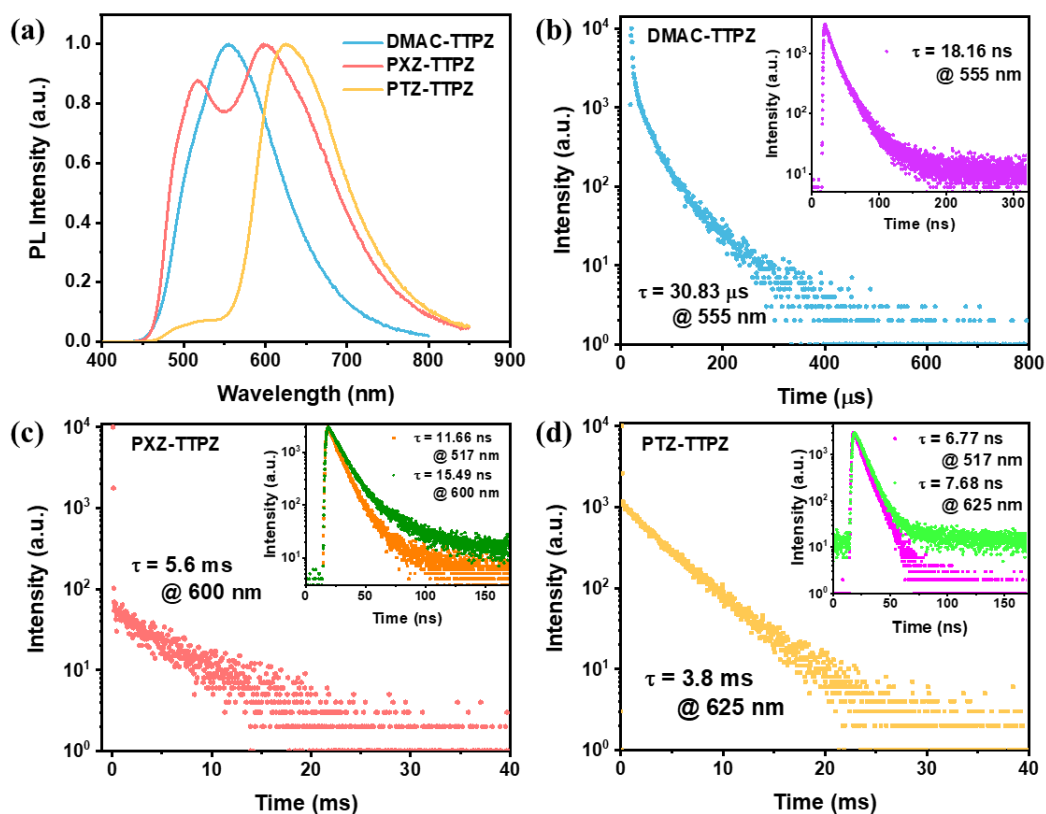


Figure S16. PL spectra (a) and time-resolved PL decay curves of DMAC-TTPZ (b), PXZ-TTPZ (c), and PTZ-TTPZ (d) in the solid state.

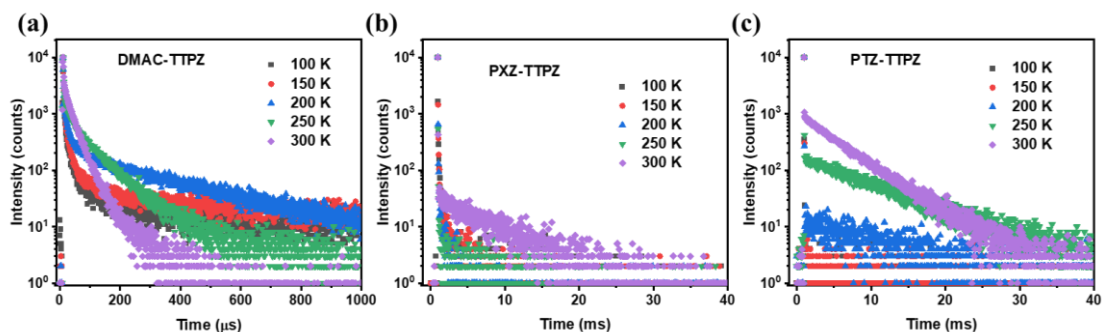


Figure S17. Time-resolved PL decay curves of DMAC-TTPZ (d), PXZ-TTPZ (e), and PTZ-TTPZ (f) in the solid state at different temperatures.

Table S1. Photodynamic parameter of PXZ-TTPZ.

Compound	k_p [s^{-1}]	k_d [s^{-1}]	k_r [s^{-1}]	k_{ISC} [s^{-1}]	k_{RISC} [s^{-1}]
PXZ-TTPZ	4.4×10^7	1.0×10^5	9.5×10^6	2.6×10^7	2.5×10^5

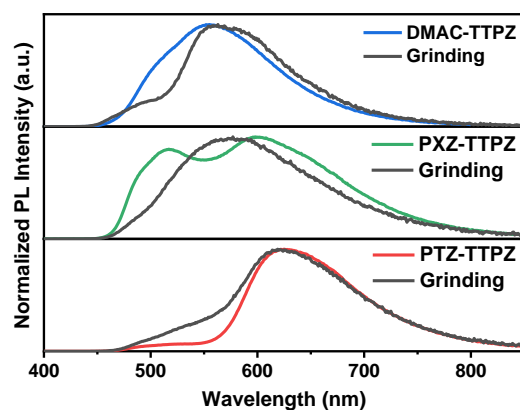


Figure S18. PL spectra of DMAC-TTPZ, PXZ-TTPZ, and PTZ-TTPZ before and after grinding.

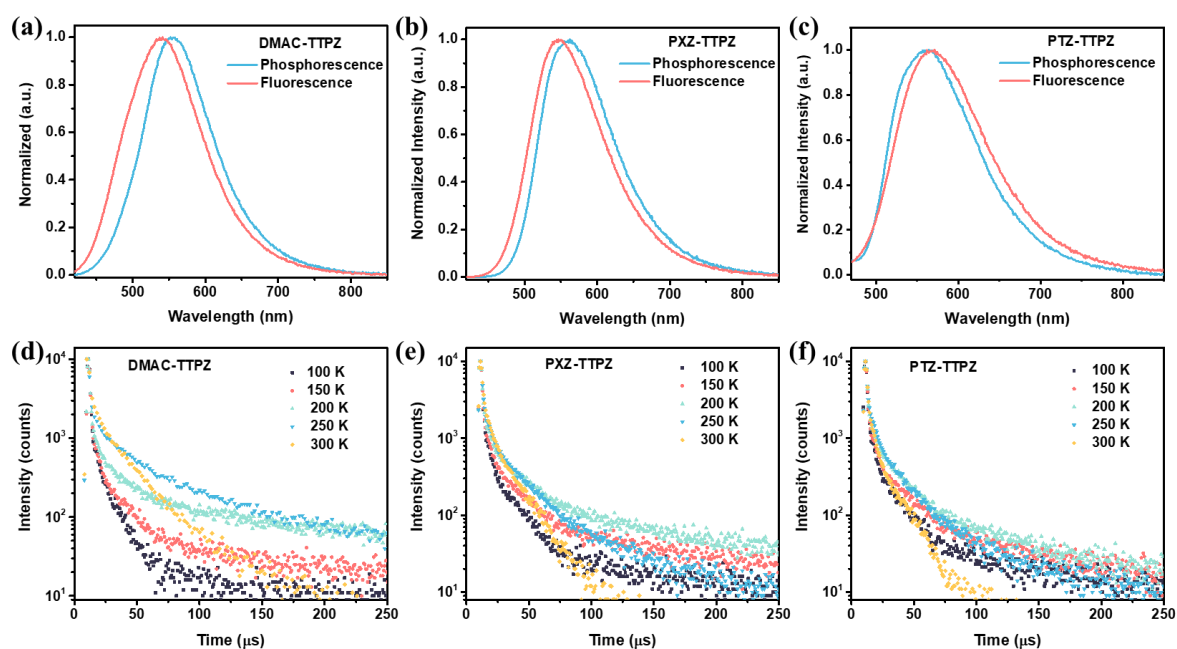


Figure S19. Fluorescence (298 K) and phosphorescence (77 K) spectra of DMAC-TTPZ (a), PXZ-TTPZ (b), and PTZ-TTPZ (c) in the doped PMMA film (5 wt%). Time-resolved PL decay curves of DMAC-TTPZ (d), PXZ-TTPZ (e), and PTZ-TTPZ (f) in the doped PMMA film (5 wt%) at different temperatures.

5. Device Performances

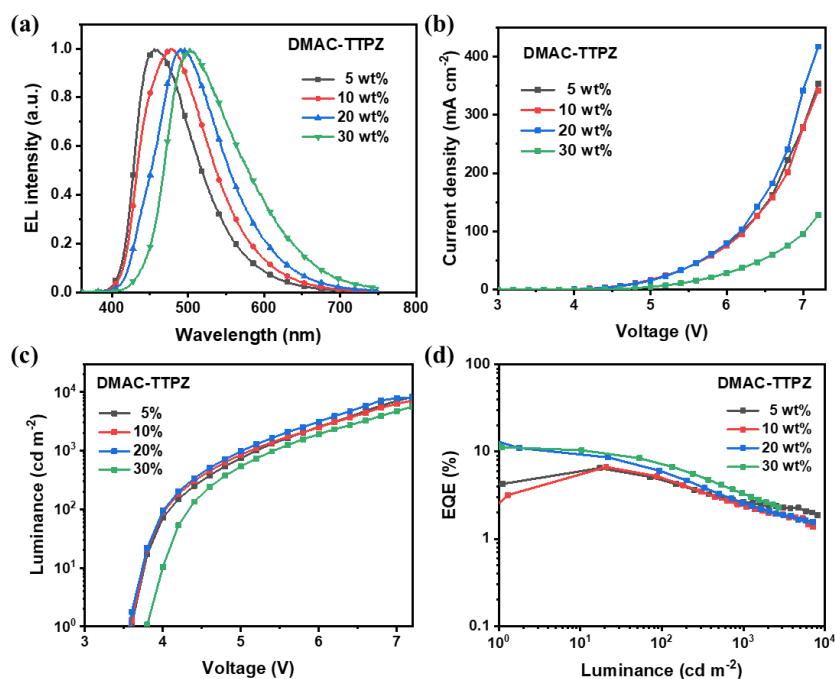


Figure S20. EL spectra (a), current density (b) and luminance (c) as a function of voltage, and EQE versus luminance of DMAC-TTPZ with different doping ratios in OLEDs.

Table S2. Summary of OLED characteristics based on DMAC-TTPZ.

Concentration (wt%)	V _{on} (V)	EQE _{max} (%)	PE _{max} (lm W ⁻¹)	CIE	λ _{max} (nm)	FWHM (nm)
5	3.6	6.5	11.9	(0.18, 0.21)	456	90
10	3.6	6.7	13.5	(0.19, 0.28)	478	104
20	3.6	11.0	23.5	(0.23, 0.37)	490	102
30	3.8	11.2	22.1	(0.29, 0.46)	502	111

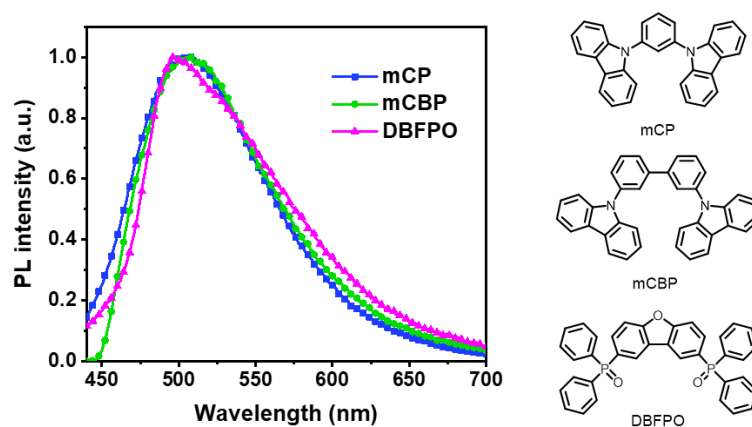


Figure S21. PL spectra of DMAC-TTPZ doped in mCP, mCBP, and DBFPO (5 wt%).

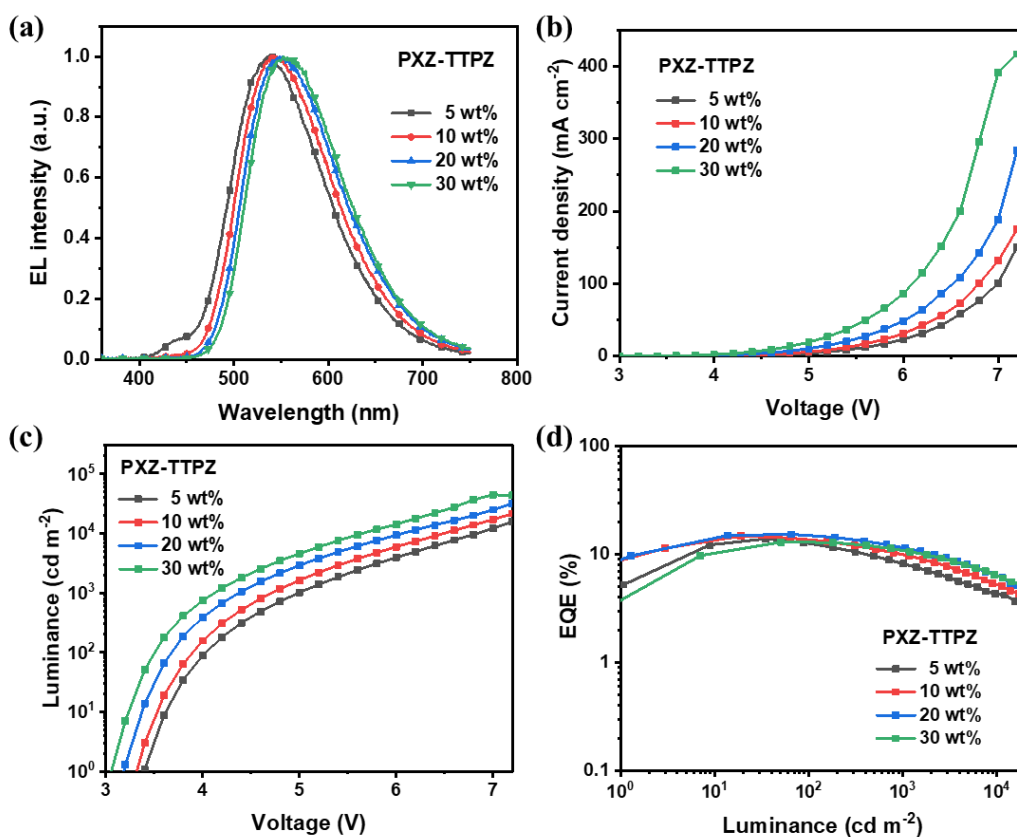


Figure S22. EL spectra (a), current density (b) and luminance (c) as a function of voltage, and EQE versus luminance of PXZ-TTPZ with different doping ratios in OLEDs.

Table S3. Summary of OLED characteristics based on PXZ-TTPZ.

Concentration (wt%)	V_{on} (V)	EQE_{max} (%)	PE_{max} (lm W^{-1})	CIE	λ_{max} (nm)	FWHM (nm)
5	3.4	13.9	35.5	(0.36, 0.53)	536	113
10	3.4	14.8	39.1	(0.39, 0.55)	546	114
20	3.2	15.3	41.0	(0.42, 0.54)	551	116
30	3.2	13.0	35.2	(0.43, 0.54)	553	116

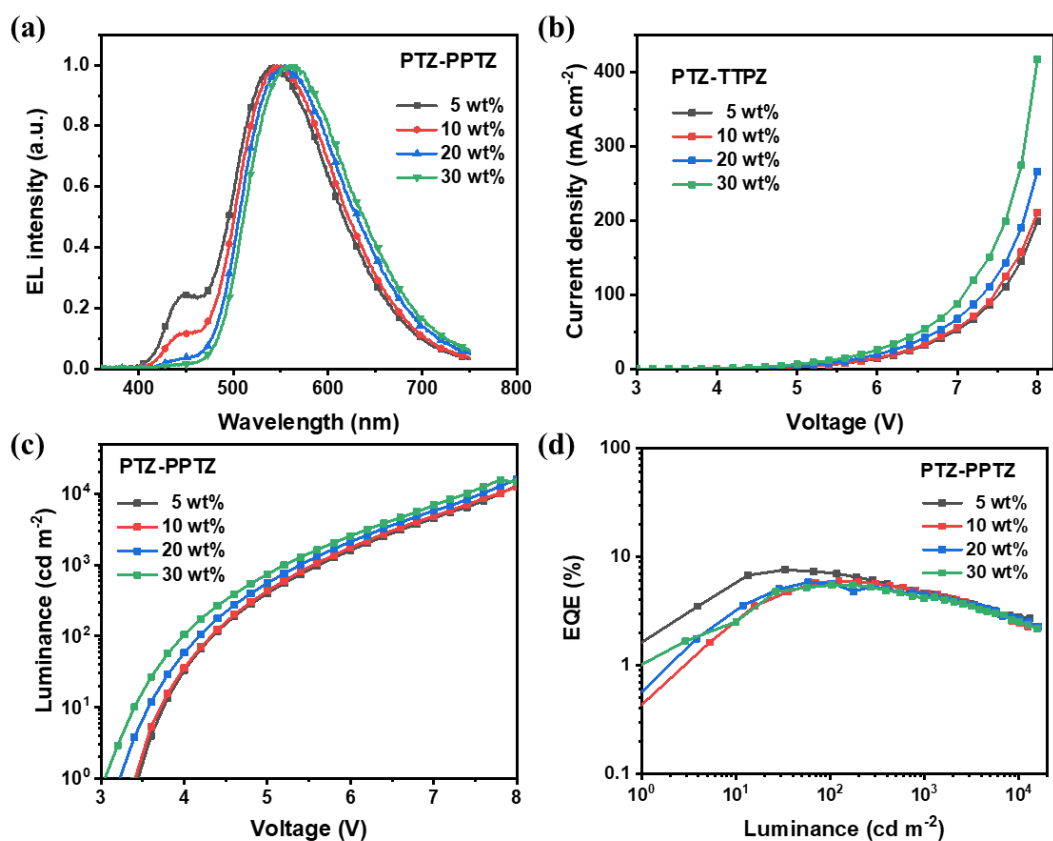


Figure S23. EL spectra (a), current density (b) and luminance (c) as a function of voltage, and EQE versus luminance of PTZ-TTPZ with different doping ratios in OLEDs.

Table S4. Summary of OLED characteristics based on PTZ-TTPZ.

Concentration (wt%)	V_{on} (V)	EQE_{max} (%)	PE_{max} (lm W^{-1})	CIE	λ_{max} (nm)	FWHM (nm)
5	3.6	7.6	17.3	(0.36, 0.48)	542	121
10	3.6	6.0	12.4	(0.39, 0.51)	546	121
20	3.4	5.8	12.8	(0.42, 0.53)	554	125
30	3.2	5.5	11.8	(0.44, 0.53)	567	126